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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/658,460	09/10/2003	Myounggoo Lee	029567-00004	2221
7590 08/20/2007 ARENT FOX KINTNER PLOTKIN & KAHN, PLLC			EXAMINER	
Suite 400			MCDONALD, RODNEY GLENN	
1050 Connecticut Avenue, N.W. Washington, DC 20036-5339		·	ART UNIT	PAPER NUMBER
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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No. Applicant(s)			
	10/658,460	LEE ET AL.		
Office Action Summary	Examiner	Art Unit		
	Rodney G. McDonald	1753		
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with the	correspondence address		
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING D. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be the solution of the sol	ON. timely filed m the mailing date of this communication. JED (35 U.S.C. § 133).		
Status				
1) Responsive to communication(s) filed on <u>01 A</u> 2a) This action is FINAL . 2b) This 3) Since this application is in condition for allowed closed in accordance with the practice under E	s action is non-final. nce except for formal matters, p			
Disposition of Claims				
4) ☐ Claim(s) 1-6 is/are pending in the application. 4a) Of the above claim(s) is/are withdray 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-6 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/o				
Application Papers				
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) accomplicated any accomplicate may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Examine	epted or b) objected to by the drawing(s) be held in abeyance. So ion is required if the drawing(s) is o	ee 37 CFR 1.85(a). bjected to. See 37 CFR 1.121(d).		
Priority under 35 U.S.C. § 119				
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 				
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summan Paper No(s)/Mail D 5) Notice of Informal 6) Other:	Date		

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on August 1, 2007 has been entered.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 5 and 6 are rejected under 35 U.S.C. 102(b) as being anticipated by Miyoshi et al. (07-018431).

Regarding claim 5, Miyoshi et al. teach a bias sputtering film forming apparatus comprising an AC power source of variable output against a substrate electrode and a database stored in a control system. The control system sets a cathode voltage to a predetermined value, stores a substrate bias voltage value in the database when the substrate electrode is apart from a target by a predetermined distance and the thickness distribution of thin films on a surface of the substrate electrode corresponding to the substrate bias voltage value as reference data, and controls the out put of the power

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source such that the output is progressively varied based on bias voltage functions produced by selecting a substrate bias voltage value from the database, which renders the film thickness substantially uniform when the surface is formed. (See Abstract; Example Japanese Translation)

Regarding claim 6, Miyoshi et al. teach an apparatus further comprising a power source of variable output against the cathode, wherein the control system also varies the cathode voltage by controlling the output of the cathode power source, and the bias sputtering film forming is performed by controlling the output of the substrate power source based on the bias voltage functions. (See Abstract; Example Japanese Translation)

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to

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consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1, 3 and 4 are rejected under 35 U.S.C. 103(a) as being unpatentable over lacoponi et al. (U.S. Pat. 6,261,946) in view of Ikeda (Japan 63-278252) and Miyoshi et al. (Japan 07-018431).

Regarding claim 1, lacoponi et al. teach a bias sputtering film forming process for forming a thin film by applying both voltages of a cathode voltage and a substrate bias voltage. (Column 7 lines 51-67; Column 8 lines 1-21) A thin film is formed on a substrate whereon an irregularity is formed in the state wherein only the cathode voltage is applied. (Column 5 lines 39-41; Column 2 lines 35-44; Column 6 lines 19-23) Sputtering film forming is performed while progressively varying the substrate bias voltage so that the thickness of the thin film formed on the internal surfaces of the irregularity is substantially uniform. (Column 7 lines 66-68; Column 8 lines 1-14; Column 5 lines 42-68; Column 6 lines 1-3)

Regarding claim 3, Iacoponi et al. teach the sputtering particles coming form the target enter substantially vertically in the substrate due to the applied bias. (Column 8 lines 5-14)

Regarding claim 4, lacoponi et al. teach the layer can be used as a seed layer for subsequent electroplating. (Column 6 lines 4-11)

The differences between Iacoponi et al. and the present claims is that where the increasing is a gradually increasing (Claim 1), wherein the progressively varying

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substrate bias voltage corresponds to stored substrate bias voltage values in a database stored in a control system (Claim 1),

Regarding where the increasing is a gradually increasing (Claim 1), Ikeda teach a process where a film is formed with excellent step coverage. The film is formed by gradually increasing the power of a high-frequency bias during a sputtering process. When a sputtering process is executed while the power of a high-frequency bias is lowered, a metal is applied sufficiently to the bottom of a semiconductor substrate without damaging the semiconductor substrate. Then, the power of the high-frequency bias is increased, and a metal film 3 whose step coverage at a stepped part is excellent is formed. (See Abstract)

The motivation for gradually increasing the bias voltage is that it allows forming uniform films over stepped surfaces. (See Abstract)

Regarding wherein the progressively varying substrate bias voltage corresponds to stored substrate bias voltage values in a database stored in a control system (Claim 1), Miyoshi et al. teach a programmable controller 8 coupled to power sources for the target and substrate for controlling the biases to the target and the substrate. (See Abstract)

The motivation for utilizing a controller is that it allows controlling the substrate bias. (See Abstract)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have modified lacoponi et al. with the features of lkeda

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and Miyoshi et al. because it allows for controlling substrate bias to deposit films with good step coverage.

Claim 2 is rejected under 35 U.S.C. 103(a) as being unpatentable over lacoponi et al. in view of Ikeda and Miyoshi et al. as applied to claims 1, 3 and 4 above, and further in view of Mamoru (Japan 2000-096223).

The difference not yet discussed is where the cathode voltage is also varied, and the bias sputtering film forming is performed while varying the substrate bias voltage.

(Claim 2).

Regarding claim 2, Mamoru teach controlling the DC bias to the target during deposition. (See Mamoru Abstract) Miyoshi et al. discussed above teach controlling the substrate bias and the DC bias at the same time. (See Miyoshi et al. discussed above)

The motivation for utilizing the features of Mamoru is that it allows for preventing disconnecting of the film layer. (See Abstract)

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to have utilized the features of Mamoru because it allows for preventing disconnection of the film layer.

REMARKS:

Applicant has argued that the prior art does not teach progressive variation of the substrate bias during film deposition. Iacoponi et al., Miyoshi et al. and Ikeda al. suggest progressive variation of the substrate during deposition of the sputtered layer. (See Iacoponi et al., Miyoshi et al. and Ikeda et al. discussed above)

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Rodney G. McDonald whose telephone number is 571-272-1340. The examiner can normally be reached on M-TH with every Friday off...

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nam X. Nguyen can be reached on 571-272-1342. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

> Rodney G. McDonald Primary Examiner

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RM

August 15, 2007